

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IXTH130N20T

D(2)

FEATURES

- Drain Source Voltage-
 - : V_{DSS}= 200V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 16m Ω (Max)
- Fast Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

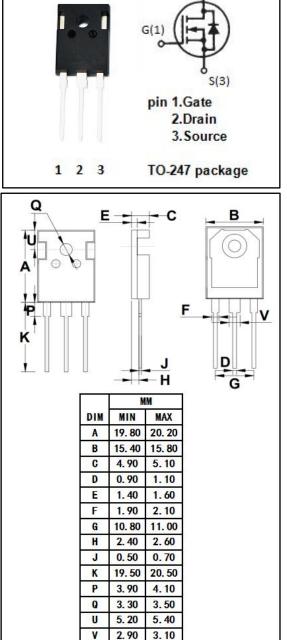
APPLICATIONS

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- AC and DC Motor Drives
- Robotics and Servo Controls

ABSOLUTE MAXIMUM RATINGS(T_a=25°C) SYMBOL PARAMETER VALUE UNIT **Drain-Source Voltage** 200 V V_{DSS} V_{GS} Gate-Source Voltage-Continuous V ± 20 **Drain Current-Continuous** I_D 130 А Drain Current-Single Plused 320 А I_{DM} PD Total Dissipation @Tc=25°C 830 W °C Τi Max. Operating Junction Temperature -55~175 -55~175 °C Storage Temperature Tstg

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.18	°C/W



isc website: www.iscsemi.com



isc N-Channel MOSFET Transistor

IXTH130N20T

• ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =250µA	200			V
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D =1mA	2.5		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 65A			16	$\mathbf{m}\Omega$
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±200	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =200V; V _{GS} = 0 V _{DS} =200V; V _{GS} = 0;TJ=150℃			25 500	μA
V _{SD}	Diode Forward On-voltage	IF= 50A ;V _{GS} = 0			1	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.